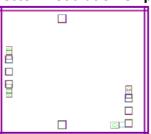
AMT1704 33-37GHz Vector Modulation Chip



Key Features:

• Frequency Range: 33 – 37GHz

• Type: single balanced

Phase modulation range: 360°

• Amplitude modulation range: -29dB ~ -13dB

Input standing wave : 1.2
Output standing wave : 1.4
Voltage bias : -0.8V ~ 0V

• Chip dimensions: 1.75mm x 1.5mm x 0.1mm

• Applications: wireless communication, transceiver module, radio telecommunication etc.

Description:

AMT1704 chip is a millimeter wave analog modulation device, it realizes signal amplitude and phase joint modulation. It is designed by Gallium Arsenide (GaAs) pHEMT process. This chip is designed with ground through metal vias on the back technology. All chip products p are 100% RF tested.

Absolute Maximum Ratings (Ta = 25°C)

<u> </u>						
Symbol	Parameter	Value	Remark			
Vi, Vq	Control Voltage	0.6V/-5V				
Pin	Input Power	20dBm				
Tm	Sintering Temperature	310°C	30s, N ₂ protection			
Tstg	Storage Temperature	-65 ~ +150°C				

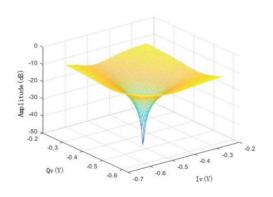
[1] Operation outside any of the Absolute Maximum Ratings may cause permanent device damage.

Electrical Characteristics (Ta = 25°C)

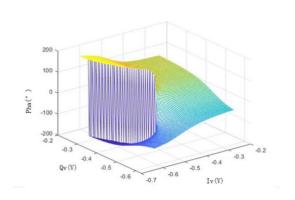
Symbol	Parameter	Value			Unit
		Min	Typical	Max	
VSWRin	Input Standing Wave	-	1.2	1.3	
VSWRout	Output Standing Wave	-	1.4	1.5	
IL	Insertion Loss	-	5.5	6	dB

Typical Performance

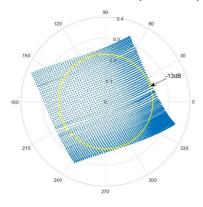
Amplitude Modulation Chart (F = 35GHz)



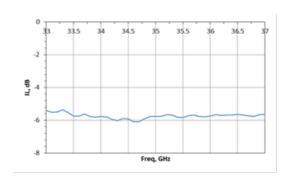
Phase Modulation Chart (F = 35GHz)

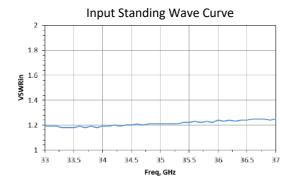


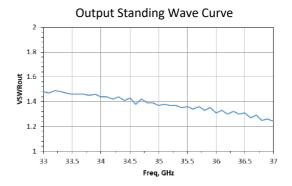
Maximum Gain Chart (F = 35GHz)



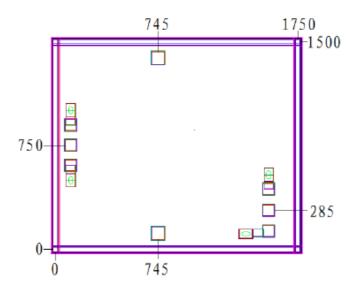
Insertion Loss



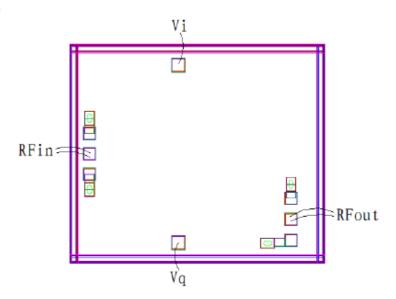




Chip Dimensions (Unit: μ m)



Chip Layout Diagram



Pad Definition

No.	Symbol	Function	PAD dimension	Explanation
1	RFin	Input point	90*90μm²	External connect to 50Ω system
2	RFout	Output point	90*90μm²	External connect to 50Ω system
3	Vi	Control point	100*100μm²	Recommend operation voltage -0.8V ~ 0V
4	Vq	Control point	100*100μm²	Recommend operation voltage -0.8V ~ 0V

Please see Appendix A for details.